4 A, 600 V, STEALTH™ Diode

Description

The ISL9R460PF2 is a STEALTH diode optimized for low loss performance in high frequency hard switched applications. The STEALTH family exhibits low reverse recovery current (I_{RR}) and exceptionally soft recovery under typical operating conditions. This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low I_{RR} and short ta phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the STEALTH diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

Features

- Ultrafast Recovery, t_{RR} = 17 ns (@ I_F = 4 A)
- Max Forward Voltage, $V_F = 2.4 \text{ V}$ (@ $T_C = 25^{\circ}\text{C}$)
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- This Device is Pb-Free and is RoHS Compliant

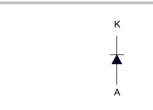
Applications

- SMPS
- Hard Switched PFC Boost Diode
- UPS Free Wheeling Diode
- Motor Drive FWD
- SMPS FWD
- Snubber Diode



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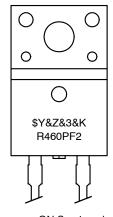
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TO-220, 2-Lead CASE 221AS

MARKING DIAGRAM



\$Y &Z&3 = ON Semiconductor Logo= Data Code (Year & Week)

&K = Lot

R460PF2

= Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

DEVICE MAXIMUM RATINGS $T_C = 25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Rating | Unit |
|-----------------------------------|----------------------------------------------------------------------------------------------------------------------------|------------|----------|
| V_{RRM} | Peak Repetitive Reverse Voltage | | V |
| V_{RWM} | Working Peak Reverse Voltage | 600 | V |
| V _R | DC Blocking Voltage | | V |
| I _{F(AV)} | Average Rectified Forward Current (T _C = 108°C) | | Α |
| I _{FRM} | Repetitive Peak Surge Current (20 kHz Square Wave) | | Α |
| I _{FSM} | Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60 Hz) | | Α |
| P_{D} | Power Dissipation | 22 | W |
| E _{AVL} | Avalanche Energy (0.5 A, 80 mH) | 10 | mJ |
| T _J , T _{STG} | Operating and Storage Temperature Range | -55 to 175 | °C |
| T _L T _{PKG} | Maximum Temperature for Soldering Leads at 0.063in (1.6 mm) from Case for 10s Package Body for 10s, See Techbrief TB334 | 300 260 | °C °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

PACKAGE MARKING AND ORDERING INFORMATION

| Part Number | Top Mark | Package | Packing Method | Reel Size | Tape Width | Quantity |
|-------------|----------|------------|----------------|-----------|------------|----------|
| ISL9R460PF2 | R460PF2 | TO-220F-2L | Tube | N/A | N/A | 50 |

ELECTRICAL CHARACTERISTICS $T_C = 25^{\circ}C$ unless otherwise noted

| Parameter | Conditions | | | | Тур | Max | Unit | |
|---------------------------|---------------------------------------------------|------------------------------------------------|-------------------------------------------------------------------------------------------------------------|---|-----|-----|------|--|
| OFF STATE CHARACTERISTICS | | | | | | | | |
| I _R | Instantaneous Reverse Current | V _R = 600 V | T _C = 25°C | - | - | 100 | μΑ | |
| | | | T _C = 125°C | - | - | 1.0 | mA | |
| ON STATE CH | ARACTERISTICS | | | | | | | |
| V _F | Instantaneous Forward Voltage | I _F = 4 A | T _C = 25°C | - | 2.0 | 2.4 | V | |
| | | | T _C = 125°C | - | 1.6 | 2.0 | V | |
| DYNAMIC CHA | ARACTERISTICS | | | | | | | |
| CJ | Junction Capacitance | V _R = 10 V, I _F = | V _R = 10 V, I _F = 0 A | | 19 | - | pF | |
| SWITCHING C | HARACTERISTICS | | | | - | | | |
| t _{RR} | Reverse Recovery Time | $I_F = 1 A, di_F/dt$ | $I_F = 1 \text{ A, di}_F/\text{dt} = 100 \text{ A/}\mu\text{s, V}_R = 30 \text{ V}$ | | 17 | 20 | ns | |
| | | I _F = 4 A, dI _F /dt V | $I_F = 4 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$ | | 19 | 22 | ns | |
| t _{RR} | Reverse Recovery Time | I _F = 4 A, | $I_F = 4 \text{ A},$ $di_F/dt = 200 \text{ A/}\mu\text{s},$ $V_R = 390 \text{ V}, T_C = 25^{\circ}\text{C}$ | | 17 | - | ns | |
| I _{RR} | Reverse Recovery Current | | | | 2.6 | - | Α | |
| Q _{RR} | Reverse Recovered Charge | VH = 390 V, 1C = 23 0 | | - | 22 | - | nC | |
| t _{RR} | Reverse Recovery Time | I _F = 4 A, | | - | 77 | - | ns | |
| S | Softness Factor (t _b /t _a) | | di _F /dt = 200 A/μs, V _R = 390 V, T _C = 125°C | | 4.2 | - | | |
| I _{RR} | Reverse Recovery Current | 10 - 123 0 | | | 2.8 | - | Α | |
| Q _{RR} | Reverse Recovered Charge | | | | 100 | - | nC | |

ELECTRICAL CHARACTERISTICS T_C = 25°C unless otherwise noted (continued)

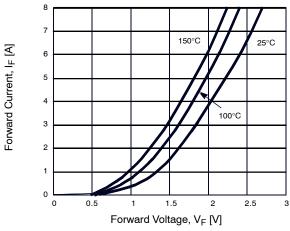
| Parameter | Conditions | | | Тур | Max | Unit | | |
|--------------------------|---------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------|---|-----|-----|------|--|--|
| WITCHING CHARACTERISTICS | | | | | | | | |
| t _{RR} | Reverse Recovery Time | $\begin{aligned} &I_F = 4 \text{ A,} \\ &di_F/dt = 400 \text{ A/}\mu\text{s, V}_R = 390 \text{ V,} \\ &-T_C = 125^{\circ}\text{C} \end{aligned}$ | - | 54 | - | ns | | |
| S | Softness Factor (t _b /t _a) | | - | 3.5 | - | | | |
| I _{RR} | Reverse Recovery Current | | - | 4.3 | - | Α | | |
| Q _{RR} | Reverse Recovered Charge | | | 110 | - | nC | | |
| dI _M /dt | Maximum di/dt during t _b | 1 | - | 500 | - | A/μs | | |
| HERMAL CHARACTERISTICS | | | | | | | | |
| Rejc | Thermal Resistance Junction to Case | | - | - | 5.7 | °C/W | | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TO-220F

TYPICAL PERFORMANCE CURVES

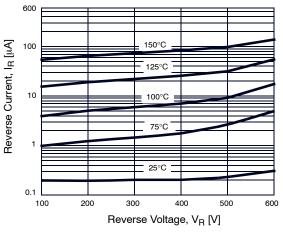
 $T_C = 25^{\circ}C$ unless otherwise noted



Thermal Resistance Junction to Ambient

Reja

Figure 1. Forward Current vs Forward Voltage



°C/W

70

Figure 2. Reverse Current vs Reverse Voltage

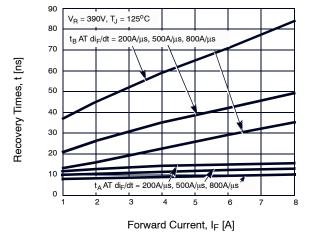
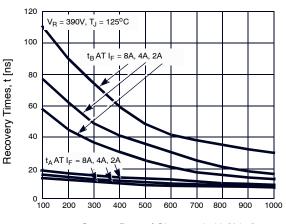


Figure 3. t_A and t_B Curves vs Forward Current

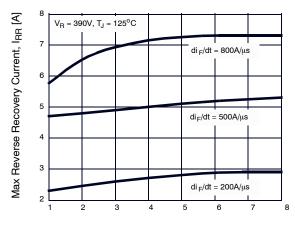


Current Rate of Change, di_F/dt [A/µs]

Figure 4. $t_{\mbox{\scriptsize A}}$ and $t_{\mbox{\scriptsize B}}$ Curves vs $di_{\mbox{\scriptsize F}}/dt$

TYPICAL PERFORMANCE CURVES (continued)

 $T_C = 25^{\circ}C$ unless otherwise noted



Forward Current, I_F [A]

Figure 5. Maximum Reverse Recovery Current vs Forward Current

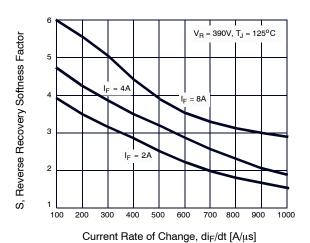


Figure 7. Reverse Recovery Softness vs di_F/dt

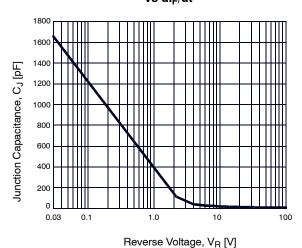
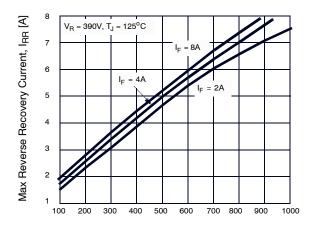
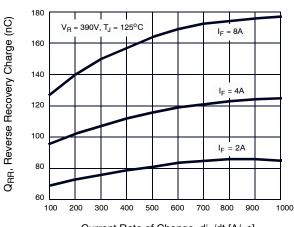


Figure 9. Junction Capacitance vs Reverse Voltage



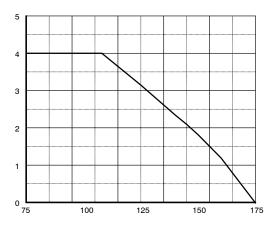
Current Rate of Change, di_F/dt [A/µs]

Figure 6. Maximum Reverse Recovery Current vs di_F/dt



Current Rate of Change, di_F/dt [A/µs]

Figure 8. Reverse Recovery Charge vs di_F/dt



Case Temperature, T_C [°C]

Figure 10. DC Current Derating Curve

Average Forward Current, I_{F(AV)} [A]

TYPICAL PERFORMANCE CURVES (continued)

 $T_C = 25^{\circ}C$ unless otherwise noted

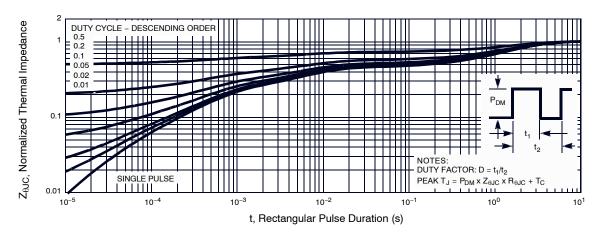


Figure 11. Normalized Maximum Transient Thermal Impedance

TEST CIRCUIT AND WAVEFORMS

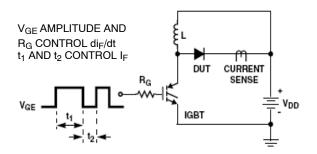


Figure 12. It_{RR} Test Circuit

 $\begin{array}{c|c} & dI_F \\ \hline I_F & dI \\ \hline & & & \\ \hline & & & \\ \hline & & & \\ & & & \\ \hline & & & \\ & & & \\ \hline & \\ \hline & \\ \hline & \\ \hline & & \\ \hline & \\ \hline$

Figure 13. t_{RR} Waveforms and Definitions

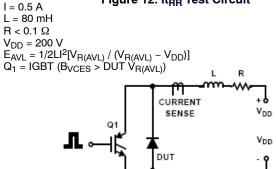


Figure 14. Avalanche Energy Test Circuit

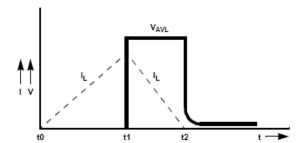


Figure 15. Avalanche Current and Voltage Waveforms

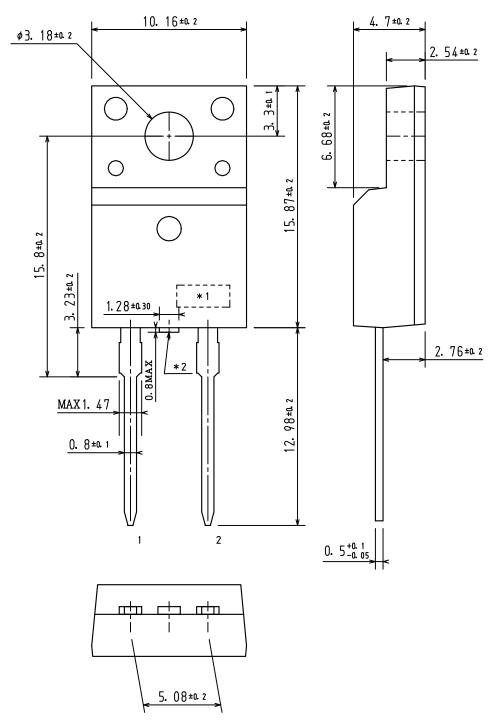
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